

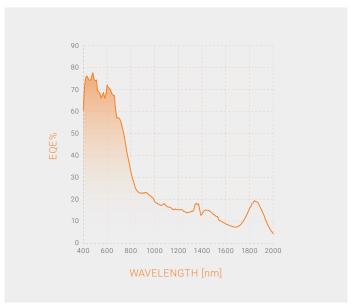
Broaden your vision

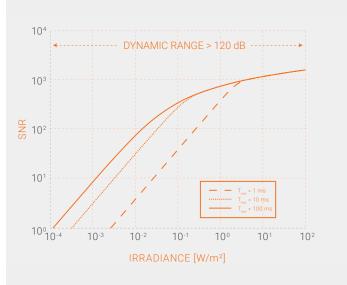
- Wide spectral range from VIS to SWIR up to 2000 nm with one image sensor from Emberion
- · Complete camera core system to provide optimal imaging solutions and ready-made for system integration
- High Dynamic Range (HDR) without saturation and capability for linear output for optical measurement are targeted for a variety of imaging application needs
- Scalability, affordability and customizability is enabled by monolithic integration of colloidal quantum dots (CQD) using in-house designed CMOS readout IC

Image sensor specifications	
Image sensor type	Emberion colloidal quantum dot (CQD) photodiode
Spectral range	400 to 2000 nm
Pixel pitch	20.0 μm x 20.0 μm
Resolution in pixels	640 x 512
Image size	12.80 mm x 10.24 mm
Image diameter	16.39 mm
Fill factor	90 %
Operable pixels	> 99.9%
Shutter	Global, built-in electronic
Cooling	Built-in thermoelectric cooler (TEC)
Camera specifications	
A/D conversion	14 bits
Image processing	Non-uniformity correction, linearisation, defect pixel correction
Exposure time	Min 0.1 ms, adjustable with 1 μs resolution
Ambient operating temperature	-20 to +40 °C
Power consumption	14 W at 400 fps
Mechanics	
Dimensions (L x W x H)	82.8 mm x 40.0 mm x 40.0 mm
Lens mount / heat sink (C-mount)	Optional
Weight	102 g for sensor and PCBA only, 251 g including lens mount / heat sink



InterfacesImage dataGigE Vision, RJ45 connectorCommunicationsGenICam compatibleFirmware updatethrough GigE interfaceMax frame rate (full VGA)400 fpsTrigger2 HW triggers (Opto-isolated and non-isolated), Trigger over Ethernet (IEEE 1588 PTP)Power input12 VDC





Camera external quantum efficiency (EQE) vs. wavelength at $0\,^{\circ}\text{C}$ sensor temperature

Camera signal-to-noise (SNR) ratio vs. irradiance at 1850 nm wavelength and F#=1 $\,$

Image sensor performance at sensor temperature 0°C

Dynamic range (optical input)	120 dB
Responsivity	$1.5\mathrm{x}10^{9}\mathrm{V/W}$ at 10 ms exposure time and 1850 nm wavelength
Input refered voltage noise	200 μV
Saturation current density	1 x 10 ⁻⁴ mA/cm ²
Noise equivalent irradiance (NEI)	3 x 10 ⁻⁴ W/m ² at 10 ms exposure time and 1850 nm wavelength

Mechanics design, dimensions and connectors

